### **Energous EN3210 Power Amplifier**

# Boosting Wireless Power with Precision and Efficiency

The EN3210 is a high-power, high-efficiency CMOS RF power amplifier optimized for use with the EN4100 Transmitter SoC. Together, they form the heart of Energous' wireless power transmitter architecture—delivering consistent, closed-loop wireless power to IoT devices, sensors, and tags.

With integrated power detectors, temperature sensing, and SPI-based control, the EN3210 provides real-time adaptability and robust RF performance for industrial-grade wireless power delivery.

Designed for wireless edge devices like ESLs, RFID tags, and low-power sensors, the EN3210 enables scalable deployment of RF-based wireless power in environments that demand reliability, minimal maintenance, and small form factors.

#### **Key Benefits**

- RF-based power transmission smaller footprint than coilbased systems
- Orientation & spatial freedom no need for precise alignment
- Eliminates mechanical connectors ideal for sealed, waterproof designs
- Integrated power management fewer external components required
- Secure communication supports 2-way authentication with 128-bit encryption
- Simplified design architecture requires only an external crystal and PA



#### **Product Highlights**

- Single-channel CMOS RF power amplifier
- Input and output power detectors
- Integrated temperature sensor
- Analog multiplexer
- Adjustable via SPI-compatible serial interface
- Designed to pair with EN4100 Transmitter
  SoC



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### **Device Overview**

Category	Specification
Amplifier Type	Single-channel CMOS RF PA
Interface	SPI
Detectors	Input and output power monitoring
Sensors	Integrated temperature sensor
Voltage Supply	1.0V, 1.8V and 3.3V
Temperature Range	Chip Level: -40C to 85C System level: -20C to 60C
Form Factor	QFN40P600X600X80-49N



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